NEC

PNP SILICON TRANSISTOR 2SA952

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DESCRIPTION

The 2SA952 is designed for use in output stage of portable radio and cassette type tape recorder, general purpose applications.

FEATURES

• High total power dissipation.

 $P_T = 600 \text{ mW}$

High h_{FE} and low V_{CE(sat)}.

 $h_{FE} (I_C = -100 \text{ mA}) : 200 \text{ TYP}.$ $V_{CE(sat)}$ (-700 mA) : -0.25 V TYP.

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures Storage Temperature - 55 to +150 °C Junction Temperature +150 °C Maximum

Maximum Power Dissipation (Ta = 25 °C) Total Power Dissipation 600 mW Maximum Voltages and Currents (Ta = 25 °C)

V_{CBO} Collector to Base Voltage -30

V_{CEO} Collector to Emitter Voltage -25 V_{EBO} Emitter to Base Voltage -5.0 mΑ lc Base Current -150

PACKAGE DIMENSIONS in millimeters (inches) 5.2 MAX. (0.204 MAX.) 5.5 N (0.216 P (0.018)(0.10)1.27 (0.05)MAX. 4.2 A EIAJ : SC-43B JEDEC: TO-92 1. EMITTER 2. COLLECTOR

ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
hFE1*	DC Current Gain	90	200	400	-	V _{CE} = -1.0 V, I _C = -100 mA
hFE2*	DC Current Gain	50	100		-	$V_{CE} = -1.0 \text{ V}, I_{C} = -700 \text{ mA}$
C _{ob}	Collector to Base Capacitance		17	40	pF	$V_{CB} = -6.0 \text{ V}, I_{E} = 0$ f = 1.0 MHz
fT	Gain Bandwidth Product	50	160		MHz	$V_{CE} = -6.0 \text{ V, } I_{E} = 10 \text{ mA}$
V _{BE} *	Base to Emitter Voltage	-600	-640	-700	mV	$V_{CE} = -6.0 \text{ V}, I_{C} = -10 \text{ mA}$
VCE(sat)*	Collector Saturation Voltage		-0.25	-0.6	v .	$I_{C} = -700 \text{ mA}, I_{B} = -70 \text{ mA}$
V _{BE(sat)} *	Base Saturation Voltage		-0.95	-1.2	V	$I_C = -700 \text{ mA}, I_B = -70 \text{ mA}$
ICBO	Collector Cutoff Current			-100	nΑ	$V_{CB} = -30 \text{ V, } I_{E} = 0$
IEBO	Emitter Cutoff Current			-100	nA	V _{EB} =-5.0 V, I _C =0

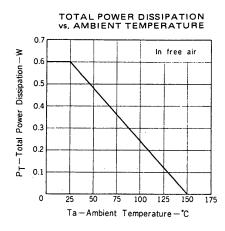
PW \leq 350 μ s, duty cycle \leq 2.0 % * Pulsed -

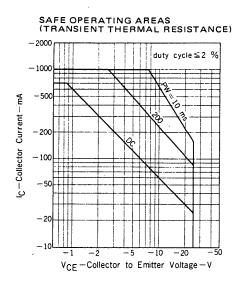
Classification of hee1

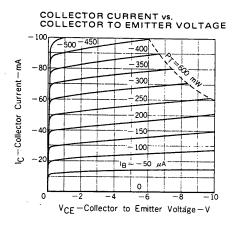
Rank	М	L	К
Range	90 – 180	135 – 270	200 – 400

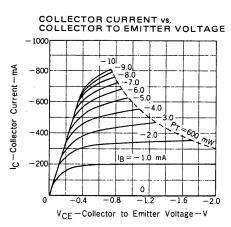
 h_{FE} Test Conditions : $V_{CE} = -1.0 \text{ V}$, $I_{C} = -100 \text{ mA}$

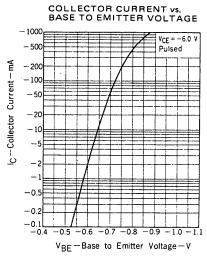
TYPICAL CHARACTERISTICS (Ta = 25 °C unless otherwise noted)

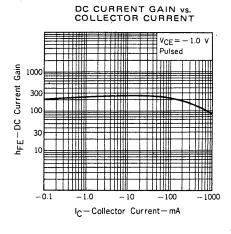


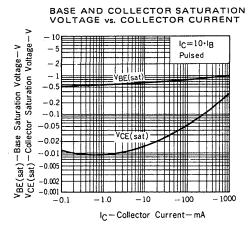


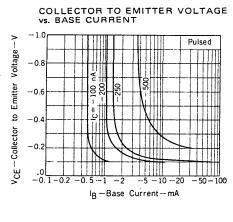


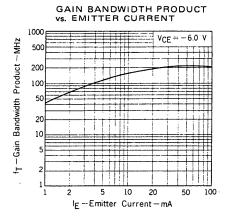












EMITTER TO BASE AND COLLECTOR TO BASE CAPACITANCE vs. REVERSE VOLTAGE

